

In situ fabricating Rh/Ga₂O₃ photothermal catalyst for dry reforming of methane

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Table S1. Surface area and average pore size of Ga₂O₃, 1% Rh₂O₃/Ga₂O₃, ZnO, and 1% Rh₂O₃/ZnO.

Catalysts	Surface area (m ² · g ⁻¹)	Average pore size (nm)
Ga ₂ O ₃	3.9	19.1
1% Rh ₂ O ₃ /Ga ₂ O ₃	4.6	21.4
ZnO	4.3	7.8
1% Rh ₂ O ₃ /ZnO	1.5	17.4

Table S2. The conversion rates of CO₂ and CH₄ were compared with other studies

Catalyst	Reaction conditions	Catalytic performance ($\mu\text{mol g}^{-1} \text{min}^{-1}$)		Stability (h)	Source
		CO ₂	CH ₄		
Rh/Ga ₂ O ₃	Photothermal	112	76.3	4	This work
Pt-Au/SiO ₂	Photothermal	68.6	54.5	1	1
Ni@SiO ₂ -yolk	Photothermal	510	480	5	2
Cu _{19.8} Ru _{0.2}	Photothermal	n.m	4.6	20	3
NiO _x	Thermal	12.8	17.1	20	4
15Ni/Al ₂ O ₃	Photothermal	38.5	46.9	5	5
Rh-Au/SBA-15	Photothermal	60	53.3	8	6
Rh/Al ₂ O ₃	Thermal	n.m	0.6	0.8	7
Co-Ce/ZrO ₂	Thermal	1.7	1.5	6	8
Pd ₉₀ Au ₁₀ /Al ₂ O ₃	Photothermal	1210.6	930.3	0.5	9
10%Rh/STO	Photothermal	2.6	2.6	13	10

Note: n.m means not mentioned

Table S3. ICP-OES detects Rh content.

Catalyst	Rh loading (wt%)
Ga ₂ O ₃	-
Rh ₂ O ₃ /Ga ₂ O ₃	0.70
ZnO	-
Rh ₂ O ₃ /ZnO	0.86

Table S4. DRM catalytic performance of 1% Rh/Ga₂O_{3-x} and 1% Rh/ZnO_{1-x} under photothermal, thermal, and light conditions.

Catalysts	Reaction condition	Reactant	Conversion ($\mu\text{mol g}^{-1}\text{min}^{-1}$)
1% Rh/Ga ₂ O _{3-x}	Photothermal	CO ₂	112
		CH ₄	76.3
	Thermal	CO ₂	71.9
		CH ₄	60.4
	Light	CO ₂	0
		CH ₄	0
1% Rh/ZnO _{1-x}	Photothermal	CO ₂	50.8
		CH ₄	39.3
	Thermal	CO ₂	49.9
		CH ₄	39.3
	Light	CO ₂	0
		CH ₄	0

Photothermal reaction conditions: CH₄ : CO₂ = 1 : 1, total flow rate: 10 mL min⁻¹, catalyst 0.094 g, reaction time 30 min, reaction temperature 500 °C, 300 W Xe lamp.

Thermal reaction conditions: CH₄ : CO₂ = 1 : 1, total flow rate: 10 mL min⁻¹, catalyst 0.094 g, reaction time 30 min, reaction temperature 500 °C.

Light reaction conditions: CH₄ : CO₂ = 1 : 1, total flow rate: 10 mL min⁻¹, catalyst 0.094 g, reaction time 30 min, 300 W Xe lamp.

Table S5. The contents of oxygen vacancy and lattice oxygen in 1% Rh₂O₃/Ga₂O₃, 1% Rh/Ga₂O_{3-x}, 1% Rh₂O₃/ZnO, 1% Rh/ZnO_{1-x} and 1% Rh₂O₃/ZrO₂, 1% Rh/ZrO₂ catalysts.

Catalysts	Oxygen vacancy	Lattice oxygen
1% Rh ₂ O ₃ /Ga ₂ O ₃	18.5%	81.5%
1% Rh/Ga ₂ O _{3-x}	25.3%	74.7%
1% Rh ₂ O ₃ /ZnO	13.1%	86.9%
1% Rh/ZnO _{1-x}	15.6%	84.4%
1% Rh ₂ O ₃ /ZrO ₂	29.3%	70.7%
1% Rh/ZrO ₂	30.5%	69.5%

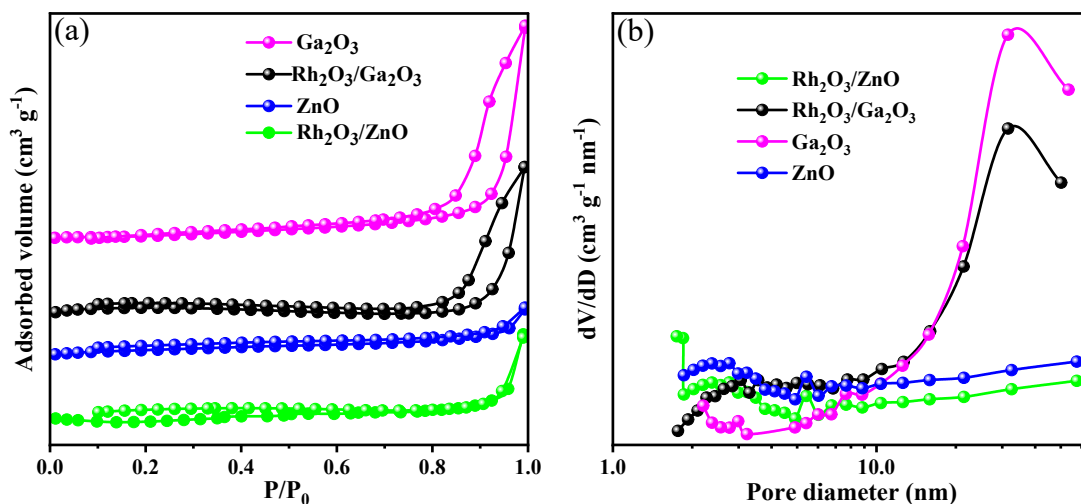


Figure S1. (a) N₂ adsorption-desorption isotherms and (b) pore size distribution of Ga₂O₃, 1% Rh₂O₃/Ga₂O₃, ZnO, and 1% Rh₂O₃/ZnO.

Note 1: All samples have the same N₂ adsorption-desorption isotherms with the IV type isotherm in IUPAC classification and observed with a loop ring of type H₃.¹¹ For Rh₂O₃/ZnO catalysts, no saturation adsorption platforms appear, indicating irregular mesopore structures of the samples.¹² BET surface area was measured to be 3.9, 4.6, 4.3, and 1.5 m² g⁻¹ for Ga₂O₃, 1% Rh₂O₃/Ga₂O₃, ZnO, and 1% Rh₂O₃/ZnO, respectively.

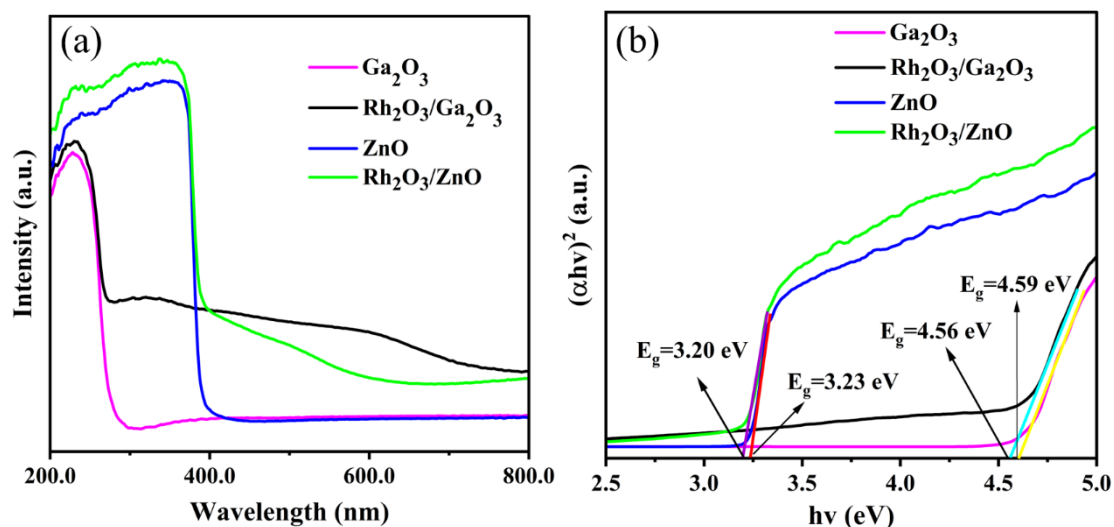


Figure S2. (a) UV-vis spectra and (b) band gap of Ga₂O₃, ZnO, 1% Rh₂O₃/Ga₂O₃, and 1% Rh₂O₃/ZnO.

Note 2: The band edges of pristine ZnO and β-Ga₂O₃ were 290 and 400 nm, corresponding to 3.23 and 4.59 eV bandgap, respectively (**Fig. S2b**). But Rh₂O₃ NPs enhanced the light absorption ability of 1% Rh₂O₃/Ga₂O₃ and 1% Rh₂O₃/ZnO, especially in the visible light range (400–800 nm) without obviously changing their band gaps.

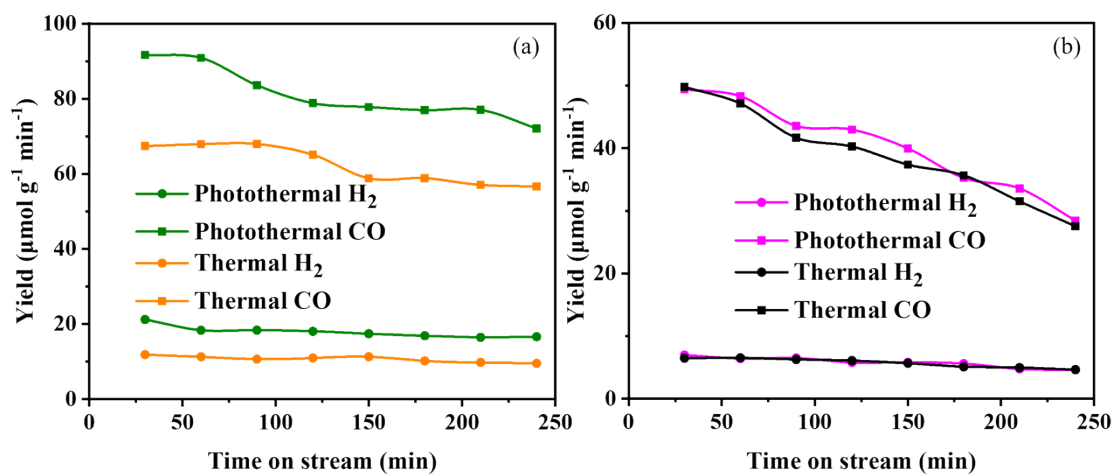


Figure S3. H₂ and CO yield on DRM reaction: (a) 1% Rh/Ga₂O_{3-x} and (b) 1% Rh/ZnO₁₋.

x. Reaction conditions: 500 °C, CH₄ : CO₂ = 1 : 1, total flow rate: 10 mL min⁻¹, 0.094 g of catalyst, with or without visible light irradiation (300 W Xe lamp).

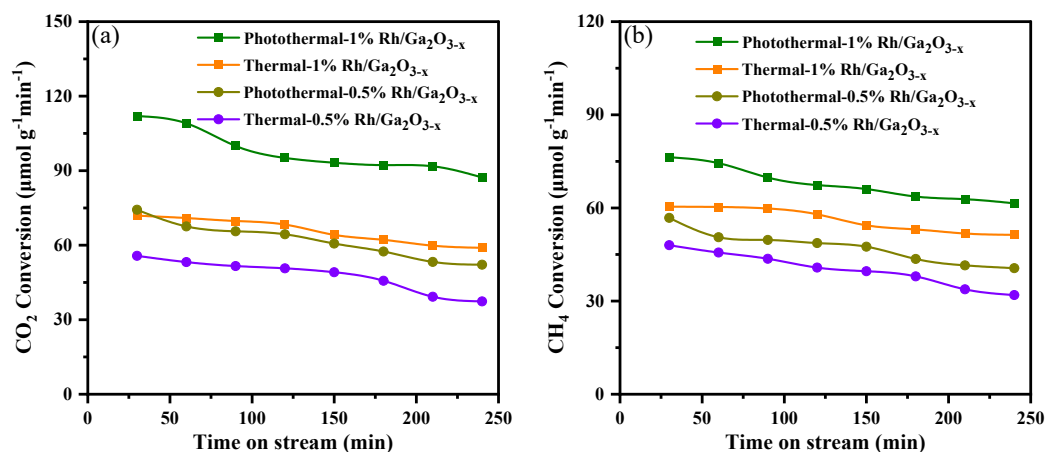


Figure S4. DRM catalytic performances over 1% Rh/Ga₂O_{3-x} and 0.5% Rh/Ga₂O_{3-x} : (a) CH₄ conversion and (b) CO₂ conversion. Reaction conditions: 500 °C, CH₄ : CO₂ = 1 : 1, total flow rate: 10 mL min⁻¹, 0.094 g of catalyst, with or without visible light irradiation (300 W Xe lamp).

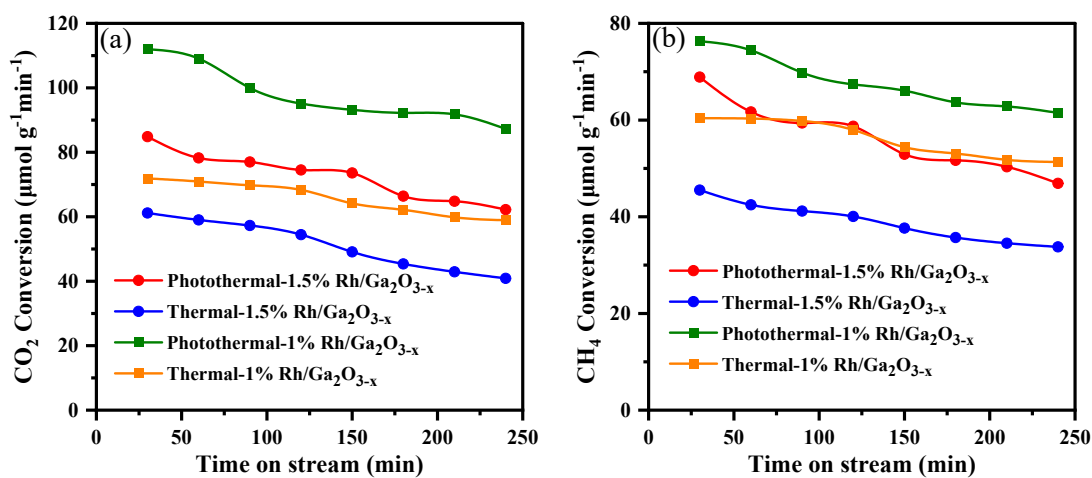


Figure S5. DRM catalytic performances over 1% Rh/Ga₂O_{3-x} and 1.5% Rh/Ga₂O_{3-x} :

(a) CH₄ conversion and (b) CO₂ conversion. Reaction conditions: 500 °C, CH₄ : CO₂ = 1 : 1, total flow rate: 10 mL min⁻¹, 0.094 g of catalyst, with or without visible light irradiation (300 W Xe lamp).

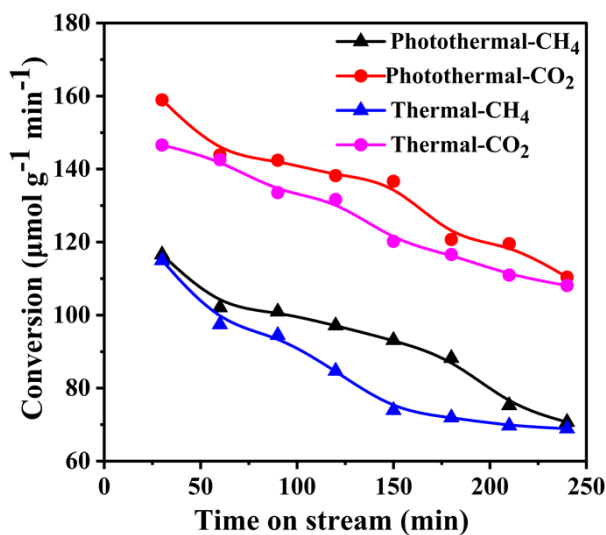


Figure S6. DRM catalytic performances over 1% Ru/Ga₂O_{3-x}: CH₄ and CO₂ conversion. Reaction conditions: 500 °C, CH₄ : CO₂ = 1 : 1, total flow rate: 10 mL min⁻¹, 0.094 g of catalyst, with or without visible light irradiation (300 W Xe lamp).

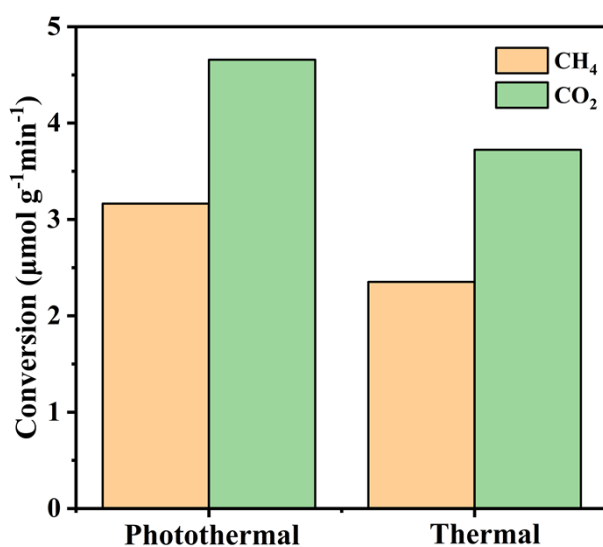


Figure S7. DRM catalytic performances over 1% Pd/Ga₂O_{3-x}. Reaction conditions: 500

°C, $\text{CH}_4 : \text{CO}_2 = 1 : 1$, total flow rate: 10 mL min^{-1} , 0.094 g of catalyst, with or without visible light irradiation (300 W Xe lamp).

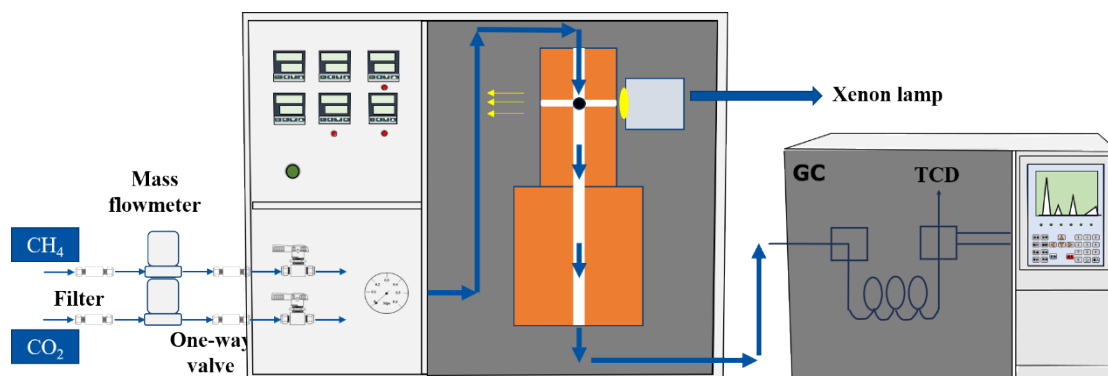


Figure S8. Fixed-bed reactor under atmospheric pressure.

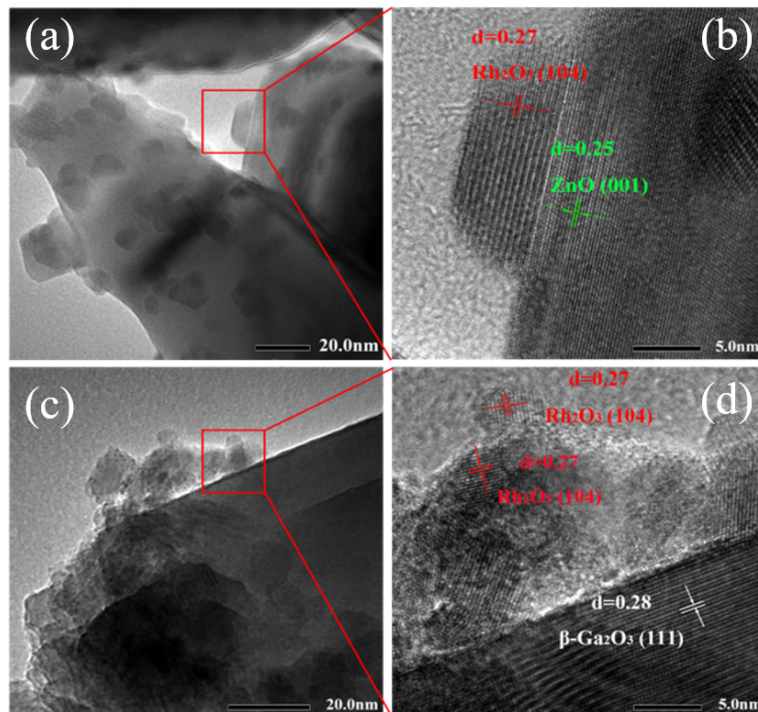


Figure S9. (a) TEM and (b) HR-TEM images of 1% $\text{Rh}_2\text{O}_3/\text{ZnO}$. (c) TEM and (d) HR-TEM images of 1% $\text{Rh}_2\text{O}_3/\text{Ga}_2\text{O}_3$.

Note 3: The morphology and crystallinity of 1% Rh₂O₃/Ga₂O₃ and 1% Rh₂O₃/ZnO samples were observed by transmission electron microscope (TEM). 1% Rh₂O₃/ZnO catalyst had a rod-like structure, and the Rh₂O₃ nanoparticles (NPs) were uniformly distributed on the ZnO surface (**Figure S9a**). The distances of clear lattice fringes were 0.27 and 0.25 nm shown on the high-resolution TEM (HRTEM) image, corresponding to Rh₂O₃ and ZnO with the good crystal structure (**Figure S9b**).¹³ Similarly, it could be observed that Rh₂O₃ NPs were loaded on β-Ga₂O₃ support (d = 0.28), meaning the successful preparation of 1% Rh₂O₃/Ga₂O₃ nanocomposite (**Figure S9c and d**).^{14, 15}

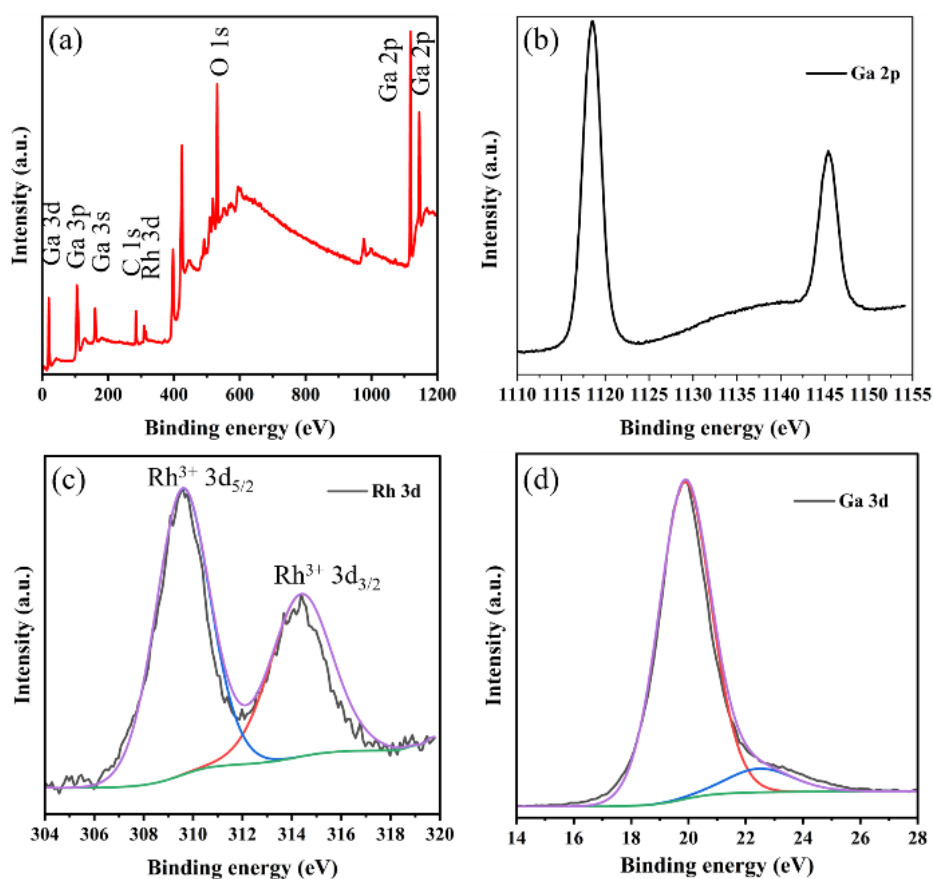


Figure S10. (a) XPS spectra of 1% Rh₂O₃/Ga₂O₃. (b) Ga 2p, (c) Rh 3d and (d) Ga 3d.

Note 4: **Figure S10a** revealed the coexistence of C, Ga, O, Rh, and N elements in 1%

Rh₂O₃/Ga₂O₃. The high-resolution XPS (HR-XPS) spectra of Ga 2p showed two peaks from Ga 2p_{3/2} and Ga 2p_{1/2} at 1118.53 eV and 1145.42 eV, respectively (**Figure S10b**).¹⁶ Compared to the β-Ga₂O₃, the characteristic peaks of Ga 2p and 3d shifted slightly to lower binding energies due to the presence of Rh₂O₃.¹⁷ Rh 3d spectra in 1% Rh₂O₃/Ga₂O₃ samples contained two peaks at 309.58 eV and 314.42 eV that can be assigned to Rh 3d_{5/2} and Rh 3d_{3/2} (**Figure S10c**).¹⁸⁻¹⁹ And a peak of Ga 3d at 19.86 eV, which was attributed to Ga³⁺, was observed in 1% Rh₂O₃/Ga₂O₃, representing the Ga–O bonding (**Figure S10d**).¹⁶

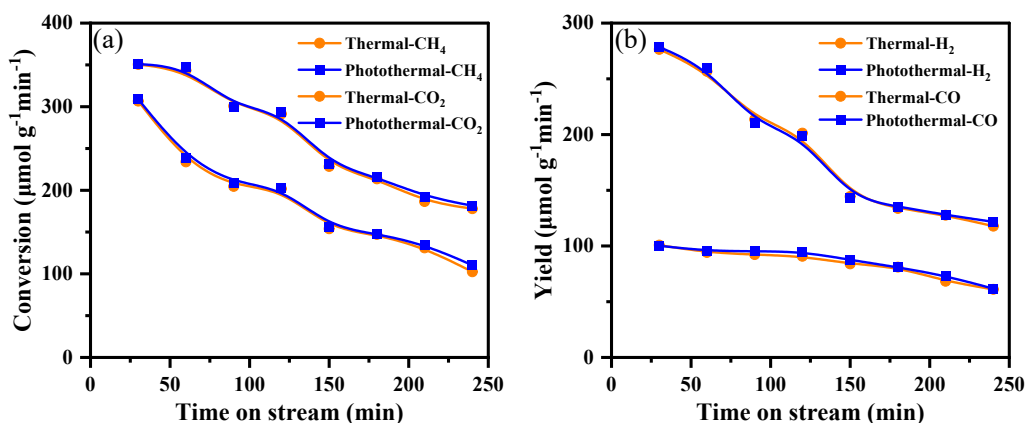


Figure S11. DRM catalytic performances over 1% Rh/ZrO₂: (a) CH₄ and CO₂ conversion and (b) H₂ and CO yield. Reaction conditions: 500 °C, CH₄ : CO₂ = 1 : 1, total flow rate: 10 mL min⁻¹, 0.094 g of catalyst, with or without visible light irradiation (300 W Xe lamp).

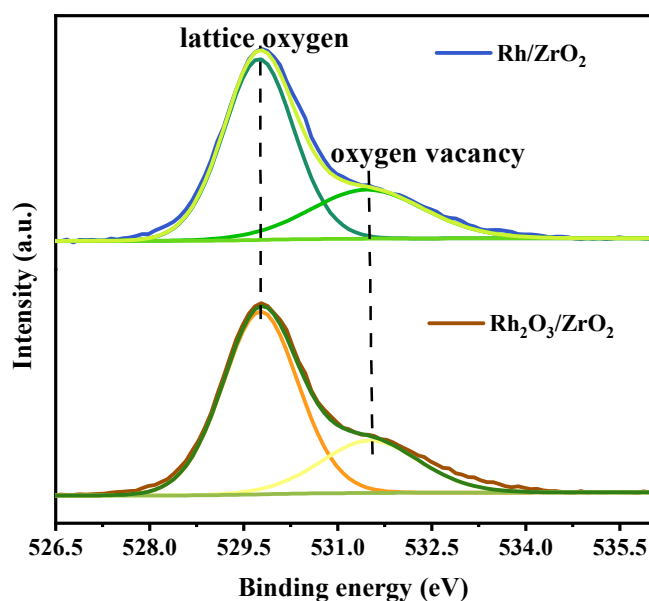


Figure S12. O1s XPS spectra of 1% Rh₂O₃/ZrO₂ and 1% Rh/ZrO₂.

Note 5: To further elucidate the role of oxygen vacancies, ZrO₂ with good stability and excellent catalytic performance was selected as the substrate to produce 1% Rh/ZrO₂ sample via the same preparation method. The DRM reactions were carried out over 1%

Rh/ZrO₂ under the same reaction conditions. The results showed that the photothermal catalytic performance of the 1% Rh/ZrO₂ catalyst was similar to thermal catalytic activity (**Figure S11**). The surface chemical properties of the catalyst were characterized by XPS (**Figure S12**), and the oxygen vacancy content of the catalyst before and after the reaction was calculated (**Table S5**). Before and after the DRM reaction, the content of oxygen vacancy in 1% Rh/ZrO₂ had only a slight variation. This indicated the enhancement effect of oxygen vacancies in the Rh/Ga₂O_{3-x} system.

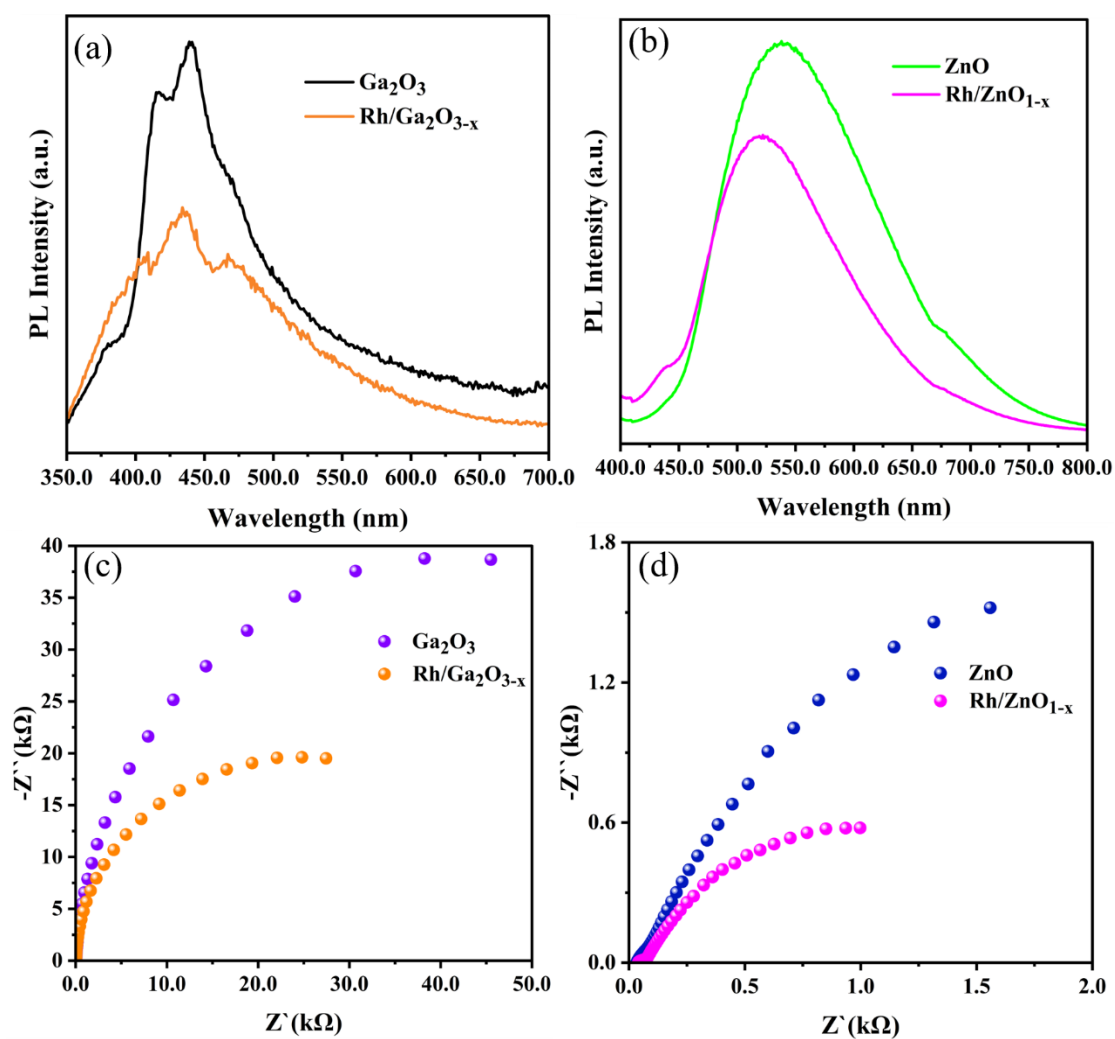


Figure S13. (a and b) PL and (c and d) EIS spectra of Ga₂O₃, 1% Rh/Ga₂O_{3-x}, ZnO and

1% Rh/ZnO_{1-x}.

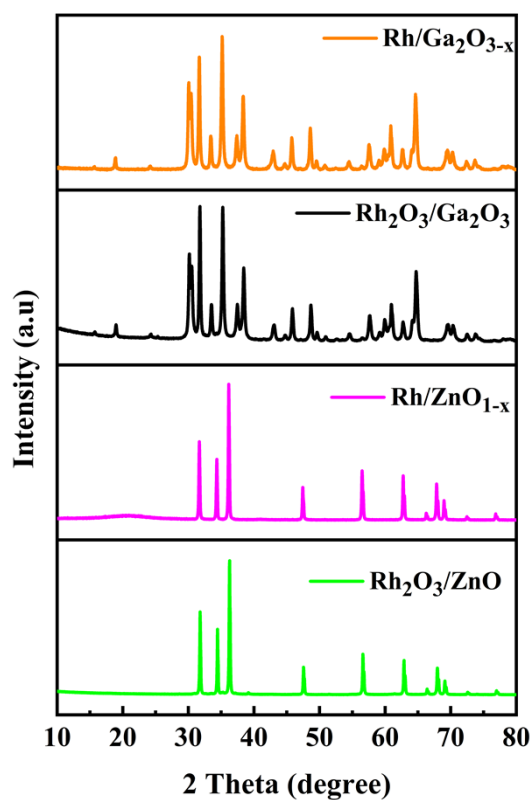


Figure S14. XRD of the fresh 1% Rh₂O₃/Ga₂O₃, 1% Rh₂O₃/ZnO the spent 1% Rh/Ga₂O_{3-x} and 1% Rh/ZnO_{1-x}.

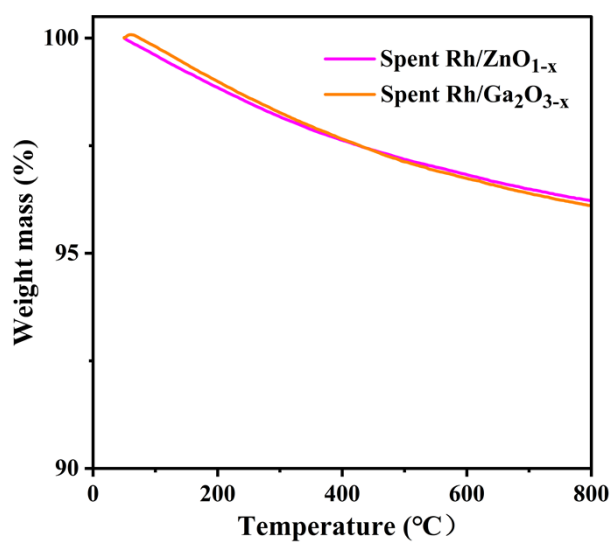


Figure S15. TG of the spent 1% Rh/Ga₂O_{3-x} and 1% Rh/ZnO_{1-x} catalysts.

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